NSN 5961-01-095-8472

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View Online at https://aerobasegroup.com/nsn/5961-01-095-8472 **Inclosure Material:** Metal **Overall Length:** 0.460 inches **Overall Diameter:** 0.610 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-61 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 325.0 collector to base voltage/static/emitter open and 300.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 30.00 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** External surfaces gold

Gold

Thread Series Designator:

Precious Material:

Unf

Terminal Type And Quantity:

1 threaded stud and 3 tab, solder lug

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N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0